

## **Smart High-Side Power Switch**

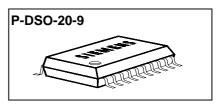
Two Channels: 2 x  $40m\Omega$ 

**Status Feedback** 

#### **Product Summary**

Operating Voltage	$V_{bb(on)}$	4.75.	41V
	Active channels	one	two parallel
On-state Resistance	R <sub>ON</sub>	$40 \text{m}\Omega$	$20 m\Omega$
Nominal load current	I <sub>L(NOM)</sub>	4.8A	7.3A
Current limitation	I <sub>L(SCr)</sub>	30A	30A

#### **Package**



#### **General Description**

- N channel vertical power MOSFET with charge pump, ground referenced CMOS compatible input and diagnostic feedback, monolithically integrated in Smart SIPMOS® technology.
- Fully protected by embedded protection functions

#### **Applications**

- µC compatible high-side power switch with diagnostic feedback for 5V, 12V and 24V grounded loads
- All types of resistive, inductive and capacitve loads
- Most suitable for loads with high inrush currents, so as lamps
- Replaces electromechanical relays, fuses and discrete circuits

#### **Basic Functions**

- Very low standby current
- CMOS compatible input
- · Fast demagnetization of inductive loads
- Stable behaviour at undervoltage
- Wide operating voltage range
- Logic ground independent from load ground

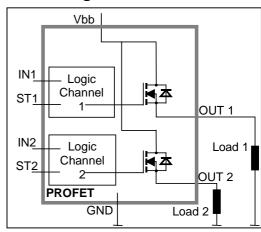
#### **Protection Functions**

- Short circuit protection
- Overload protection
- Current limitation
- Thermal shutdown
- Overvoltage protection (including load dump) with external resistor
- Reverse battery protection with external resistor
- Loss of ground and loss of V<sub>bb</sub> protection
- Electrostatic discharge protection (ESD)

#### **Diagnostic Function**

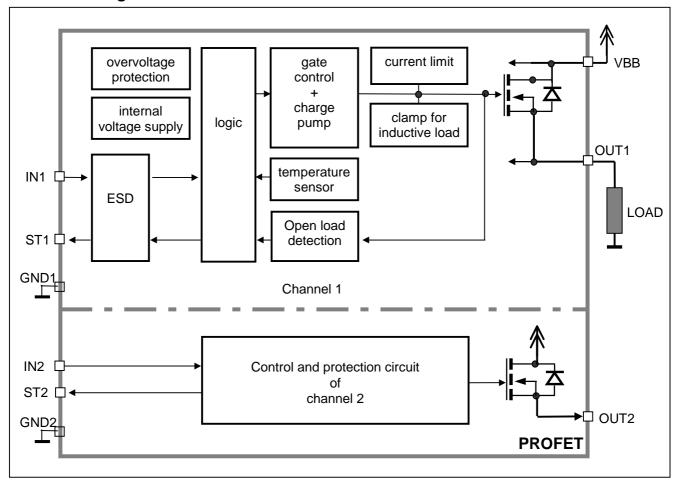
- Diagnostic feedback with open drain output
- Open load detection in ON-state
- Feedback of thermal shutdown in ON-state

#### **Block Diagram**





### **Functional diagram**



#### **Pin Definitions and Functions**

Pin	Symbol	Function
1,10,	$V_{bb}$	Positive power supply voltage. Design the
11,12,		wiring for the simultaneous max. short circuit
15,16,		currents from channel 1 to 2 and also for low
19,20		thermal resistance
3	IN1	Input 1,2, activates channel 1,2 in case of
7	IN2	logic high signal
17,18	OUT1	Output 1,2, protected high-side power output
13,14	OUT2	of channel 1,2. Design the wiring for the max.
		short circuit current
4	ST1	Diagnostic feedback 1,2 of channel 1,2,
8	ST2	open drain, low on failure
2	GND1	Ground 1 of chip 1 (channel 1)
6	GND2	Ground 2 of chip 2 (channel 2)
5,9	N.C.	Not Connected

### Pin configuration

(top view	)		
$V_{bb}$	1 •	20	$V_{bb}$
GND1	2	19	V <sub>bb</sub>
IN1	3	18	OUT1
ST1	4	17	OUT1
N.C.	5	16	$V_{bb}$
GND2	6	15	V <sub>bb</sub>
IN2	7	14	OUT2
ST2	8	13	OUT2
N.C.	9	12	$V_{bb}$
$V_{bb}$	10	11	V <sub>bb</sub>
			1



### **Maximum Ratings** at $T_i = 25$ °C unless otherwise specified

Parameter	Symbol	Values	Unit
Supply voltage (overvoltage protection see page 4)	$V_{ m bb}$	43	V
Supply voltage for full short circuit protection $T_{j,\text{start}} = -40 \dots + 150^{\circ}\text{C}$	$V_{ m bb}$	24	V
Load current (Short-circuit current, see page 5)	<i>I</i> ∟	self-limited	Α
Load dump protection <sup>1)</sup> $V_{\text{LoadDump}} = V_{\text{A}} + V_{\text{S}}, \ V_{\text{A}} = 13.5 \text{ V}$ $R_{\text{I}^2} = 2 \Omega, \ t_{\text{d}} = 200 \text{ ms}; \ \text{IN} = \text{low or high,}$ each channel loaded with $R_{\text{L}} = 9.0 \Omega,$	V <sub>Load dump</sub> 3)	60	V
Operating temperature range	$T_{\rm j}$	-40+150	°C
Storage temperature range	$T_{ m stg}$	-55+150	
Power dissipation (DC) <sup>4)</sup> $T_a = 25$ °C:	$P_{tot}$	3.8	W
(all channels active) $T_a = 85$ °C:		2.0	
Maximal switchable inductance, single pulse $V_{bb} = 12V$ , $T_{j,start} = 150^{\circ}C^{4}$ ,			
$I_L = 4.0 \text{ A}, E_{AS} = 296 \text{ mJ}, 0 \Omega$ one channel:	$Z_{L}$	19.0	mH
$I_L = 6.0 \text{ A}$ , $E_{AS} = 631 \text{ mJ}$ , $0 \Omega$ two parallel channels:		17.5	
see diagrams on page 9			
Electrostatic discharge capability (ESD) IN:	$V_{ESD}$	1.0	kV
(Human Body Model) ST: out to all other pins shorted:		4.0	
acc. MIL-STD883D, method 3015.7 and ESD assn. std. S5.1-1993 R=1.5k $\Omega$ ; C=100pF		8.0	
Input voltage (DC)	V <sub>IN</sub>	-10 +16	V
Current through input pin (DC)	I <sub>IN</sub>	±2.0	mA
Current through status pin (DC)	<i>I</i> <sub>ST</sub>	±5.0	
see internal circuit diagram page 8			

#### **Thermal Characteristics**

Parameter and Conditions		Symbol	Values			Unit	
			min	typ	Max		
Thermal resistance	and shannel				40	12/\\	
junction - soldering point <sup>4),5)</sup>	each channel:	$R_{thjs}$			12	K/W	
junction - ambient <sup>4)</sup>	one channel active:	$R_{thja}$		40			
	all channels active:			33			

<sup>1)</sup> Supply voltages higher than  $V_{bb(AZ)}$  require an external current limit for the GND and status pins (a 150 $\Omega$  resistor for the GND connection is recommended.

 $<sup>^{2)}</sup>$   $R_{I}$  = internal resistance of the load dump test pulse generator

<sup>3)</sup> V<sub>Load dump</sub> is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

<sup>4)</sup> Device on 50mm\*50mm\*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70μm thick) copper area for V<sub>bb</sub> connection. PCB is vertical without blown air. See page 14

<sup>5)</sup> Soldering point: upper side of solder edge of device pin 15. See page 14



#### **Electrical Characteristics**

Parameter and Conditions, each of the two channels		Symbol		<b>Values</b>		Unit
at T <sub>j</sub> = -40+150°C, $V_{bb}$ = 12 V unle	ess otherwise specified		min	typ	Max	
Load Switching Capabilities and Characteristics				1		
On-state resistance (V <sub>bb</sub> to O	UT); $I_L = 2 A, V_{bb} \ge 7V$					
each ch	nannel, $T_j = 25$ °C:	R <sub>ON</sub>		36	40	mΩ
	$T_{\rm j} = 150^{\circ}{\rm C}$ :			67	75	
two parallel o	channels, $T_i = 25$ °C:			18	20	
Nominal load current	one channel active:	$I_{L(NOM)}$	4.4	4.8		Α
two para	allel channels active:		6.7	7.3		
Device on PCB <sup>6</sup> ), $T_a = 85^{\circ}\text{C}$ , $T_i \le 150^{\circ}\text{C}$						
Output current while GND disconnected or pulled up; Vbb = 30 V, VIN = 0,		I <sub>L(GNDhigh)</sub>			2	mA
see diagram page 8; (not tested specified by design)						
Turn-on time <sup>7)</sup>	N $\int$ to 90% $V_{OUT}$ :	<i>t</i> on	50	100	200	μs
Turn-off time	N $\square$ to 10% $V_{OUT}$ :	$t_{ m off}$	50	120	250	
$R_{\rm L} = 12 \Omega$						
Slew rate on 7)		d V/dt <sub>on</sub>	0.1		1	V/μs
10 to 30% $V_{OUT}$ , $R_L = 12 \Omega$ :						
Slew rate off $^{7)}$ 70 to 40% $V_{OUT}$ , $R_L = 12 \Omega$ :		-d V/dt <sub>off</sub>	0.1		1	V/μs
Operating Parameters						
Operating voltage	Tj=-40	$V_{ m bb(on)}$	4.75		41	V
	T <sub>j</sub> =25150°C:				43	
Overvoltage protection <sup>8)</sup>	$T_{\rm j}$ =-40°C:	$V_{\rm bb(AZ)}$	41			V
$I_{bb} = 40 \text{ mA}$	$T_i = 25150$ °C:		43	47	52	

Operating voltage	Tj=-40	$V_{\rm bb(on)}$	4.75		41	V
	T <sub>i</sub> =25150°C:	22(0.1)			43	
Overvoltage protection <sup>8)</sup>	$T_{\rm j}$ =-40°C:	$V_{\rm bb(AZ)}$	41			V
$I_{bb} = 40 \text{ mA}$	$T_{\rm j}$ =25150°C:		43	47	52	
Standby current <sup>9)</sup>	T <sub>j</sub> =-40°C25°C:	I <sub>bb(off)</sub>		10	16	μΑ
$V_{IN} = 0$ ; see diagram page 10	$T_{\rm j}$ =150°C:				50	
Leakage output current (included in Ibb(off))		I <sub>L(off)</sub>		1	10	μΑ
VIN = 0						
Operating current <sup>10)</sup> , $V_{IN} = 5V$ ,						
$I_{\text{GND}} = I_{\text{GND1}} + I_{\text{GND2}},$	one channel on:	I <sub>GND</sub>		0.8	1.4	mA
	two channels on:			1.6	2.8	

<sup>6)</sup> Device on 50mm\*50mm\*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70μm thick) copper area for V<sub>bb</sub> connection. PCB is vertical without blown air. See page 14

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<sup>7)</sup> See timing diagram on page 11.

Supply voltages higher than  $V_{bb(AZ)}$  require an external current limit for the GND and status pins (a 150 $\Omega$  resistor for the GND connection is recommended). See also  $V_{ON(CL)}$  in table of protection functions and circuit diagram on page 8.

<sup>9)</sup> Measured with load; for the whole device; all channels off

<sup>10)</sup> Add  $I_{ST}$ , if  $I_{ST} > 0$ 

BTS 736 L2

Parameter and Conditions, each of the two channel	s <b>Symbol</b>	Values			Unit
at T <sub>j</sub> = -40+150°C, $V_{bb}$ = 12 V unless otherwise specified		min	typ	Max	
Protection Functions					
Current limit, (see timing diagrams, page 12)					
$T_{\rm j} = -40^{\circ}$	D: I <sub>L(lim)</sub>	40	49	60	Α
$T_{\rm j} = 25^{\circ}$	D:	33	41	48	
$T_{\rm j} = +150^{\circ}$	D:	23	29	35	
Repetitive short circuit current limit,					
$T_{\rm i} = T_{\rm it}$ each chann	el / <sub>L(SCr)</sub>		30		Α
two parallel channe	` '		30		
(see timing diagrams, page 12)					
Initial short circuit shutdown time $T_{j,start} = 25^{\circ}$	$C: t_{\text{off(SC)}}$		1.7		ms
(see timing diagrams on page 1	2)				
Output clamp (inductive load switch off) <sup>11)</sup>					V
at $VON(CL) = Vbb - VOUT$ , $I_L = 40 \text{ mA}$ $T_j = -40^{\circ} \text{ G}$	` '	41			
$T_{j} = 25^{\circ}\text{C}150^{\circ}\text{C}$	D:	43	47	52	
Thermal overload trip temperature	$T_{jt}$	150			°C
Thermal hysteresis	$\Delta T_{\rm jt}$		10		K
	·				
Reverse Battery		,	ı		
Reverse battery voltage 12)	- $V_{ m bb}$			32	V
Drain-source diode voltage ( $V_{out} > V_{bb}$ ) $I_L = -4.0 \text{ A}, T_j = +150 ^{\circ}\text{C}$	-V <sub>ON</sub>		600		mV

<sup>11)</sup> If channels are connected in parallel, output clamp is usually accomplished by the channel with the lowest VON(CL)

Requires a 150  $\Omega$  resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Power dissipation is higher compared to normal operating conditions due to the voltage drop across the drain-source diode. The temperature protection is not active during reverse current operation! Input and Status currents have to be limited (see max. ratings page 3 and circuit page 8).

BTS 736 L2

Parameter and Conditions, each of the two channels		Symbol		<b>Values</b>		Unit
at T <sub>j</sub> = -40+150°C, $V_{bb}$ = 12 V unless o	therwise specified		min	typ	Max	
Diagnostic Characteristics						
Open load detection current, (on-c	ondition)					
	each channel	I <sub>L (OL)</sub>	100		900	mΑ
Innut and Status Feedbast 12)						
Input and Status Feedback <sup>13)</sup>			0.5	0 = 1		
Input resistance (see circuit page 8)		$R_{I}$	2.5	3.5	6	kΩ
· · · · · · · · · · · · · · · · · · ·		1/	4.7		2.2	\/
Input turn-on threshold voltage	<u>-/</u>	$V_{IN(T+)}$	1.7		3.2	V
Input turn-off threshold voltage		$V_{IN(T-)}$	1.5			V
Input threshold hysteresis		$\Delta V_{IN(T)}$		0.5	-	V
Off state input current	$V_{IN} = 0.4 \text{ V}$ :	I <sub>IN(off)</sub>	1		50	μΑ
On state input current	$V_{IN} = 5 \text{ V}$ :	I <sub>IN(on)</sub>	20	50	90	μΑ
Delay time for status with open loa off; (see diagram on page 13)	ad after switch	t <sub>d(ST OL4)</sub>	100	520	900	μs
Status output (open drain)						
Zener limit voltage	$I_{ST} = +1.6 \text{ mA}$ :	$V_{\rm ST(high)}$	5.4	6.1		V
		, <del>-</del> ,				

 $<sup>^{\</sup>rm 13)}\,$  If ground resistors  ${\rm R}_{\rm GND}$  are used, add the voltage drop across these resistors.



#### **Truth Table**

Channel 1	Input 1	Output 1	Status 1
Channel 2	Input 2	Output 2	Status 2
	level	level	BTS 736L2
Normal	L	L	Н
operation	Н	Н	Н
Open load	L	Z	Н
	Н	Н	L
Overtem-	L	L	Н
perature	Н	L	L

L = "Low" Level

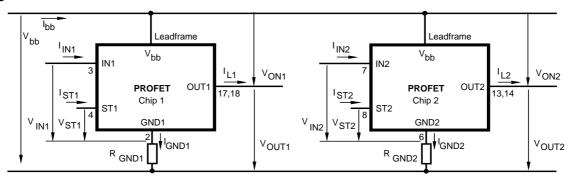
X = don't care

Z = high impedance, potential depends on external circuit

H = "High" Level Status signal valid after the time delay shown in the timing diagrams

Parallel switching of channel 1 and 2 is easily possible by connecting the inputs and outputs in parallel. The status outputs ST1 and ST2 have to be configured as a 'Wired OR' function with a single pull-up resistor.

#### **Terms**

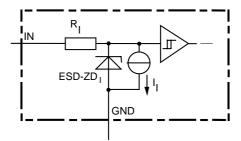


Leadframe (V<sub>bb</sub>) is connected to pin 1,10,11,12,15,16,19,20

External R<sub>GND</sub> optional; two resistors R<sub>GND1</sub>, R<sub>GND2</sub> = 150  $\Omega$  or a single resistor R<sub>GND</sub> = 75  $\Omega$  for reverse battery protection up to the max. operating voltage.

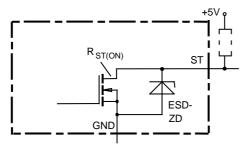


#### Input circuit (ESD protection), IN1 or IN2



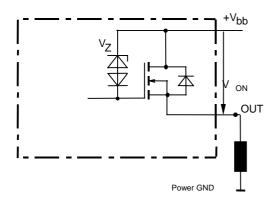
The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

#### Status output, ST1 or ST2



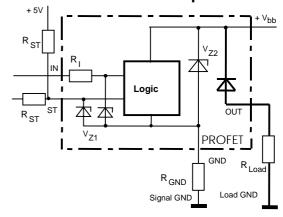
ESD-Zener diode: 6.1 V typ., max 5.0 mA;  $R_{ST(ON)}$  < 375  $\Omega$  at 1.6 mA. The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

## **Inductive and overvoltage output clamp,** OUT1 or OUT2



VON clamped to VON(CL) = 47 V typ.

#### Overvolt. and reverse batt. protection



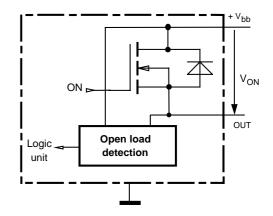
 $V_{Z1}$  = 6.1 V typ.,  $V_{Z2}$  = 47 V typ.,  $R_{GND}$  = 150 Ω,  $R_{ST}$  = 15 kΩ,  $R_{I}$  = 3.5 kΩ typ.

In case of reverse battery the load current has to be limited by the load. Temperature protection is not active

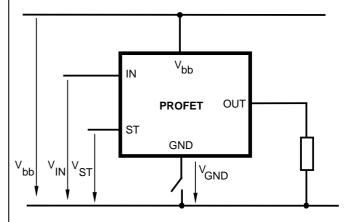
#### Open-load detection OUT1 or OUT2

ON-state diagnostic

Open load, if  $V_{ON} < R_{ON} \cdot I_{L(OL)}$ ; IN high



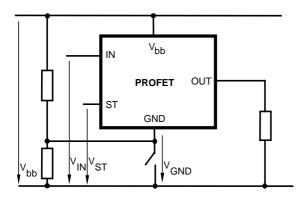
#### **GND** disconnect



Any kind of load. In case of IN=high is  $V_{OUT} \approx V_{IN} - V_{IN}(T+)$ . Due to  $V_{GND} > 0$ , no  $V_{ST} = low$  signal available.

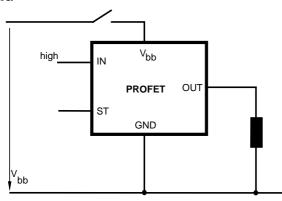


#### **GND** disconnect with GND pull up



Any kind of load. If  $V_{GND} > V_{IN} - V_{IN(T+)}$  device stays off Due to  $V_{GND} > 0$ , no  $V_{ST} = low$  signal available.

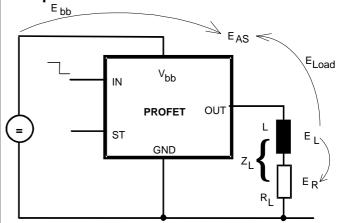
## V<sub>bb</sub> disconnect with energized inductive load



For inductive load currents up to the limits defined by  $Z_L$  (max. ratings and diagram on page 9) each switch is protected against loss of  $V_{\mbox{bb}}$ .

Consider at your PCB layout that in the case of Vbb disconnection with energized inductive load all the load current flows through the GND connection.

# Inductive load switch-off energy dissipation



Energy stored in load inductance:

$$E_{L} = \frac{1}{2} \cdot L \cdot I_{I}^{2}$$

While demagnetizing load inductance, the energy dissipated in PROFET is

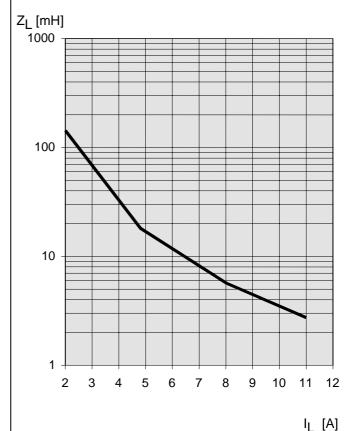
$$E_{AS} = E_{bb} + E_L - E_R = \int V_{ON(CL)} \cdot i_L(t) dt$$

with an approximate solution for  $R_L > 0 \Omega$ :

$$E_{\text{AS}} = \frac{I_{\text{L}} \cdot L}{2 \cdot R_{\text{L}}} (V_{\text{bb}} + |V_{\text{OUT(CL)}}|) \ ln \ (1 + \frac{I_{\text{L}} \cdot R_{\text{L}}}{|V_{\text{OUT(CL)}}|})$$

# Maximum allowable load inductance for a single switch off (one channel)<sup>4)</sup>

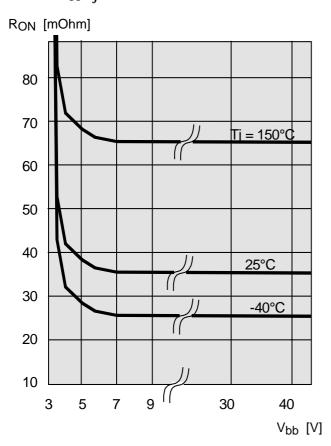
$$L = f(I_L)$$
; T<sub>j,start</sub> = 150°C, V<sub>bb</sub> = 12 V, R<sub>L</sub> = 0  $\Omega$ 





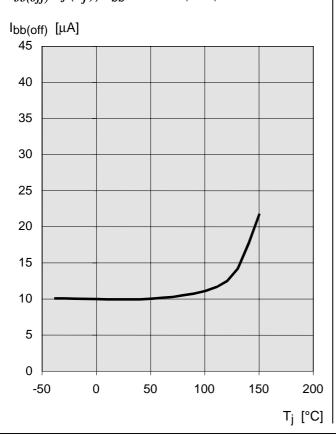
### Typ. on-state resistance

 $R_{ON} = f(V_{bb}, T_j); I_L = 2 A, IN = high$ 



### Typ. standby current

 $I_{bb(off)} = f(T_j); V_{bb} = 9...34 \text{ V}, \text{IN1,2} = \text{low}$ 



## **SIEMENS**

## **Timing diagrams**

Both channels are symmetric and consequently the diagrams are valid for channel 1 and channel 2

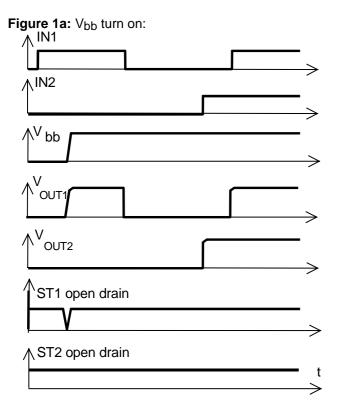


Figure 2a: Switching a resistive load, turn-on/off time and slew rate definition:

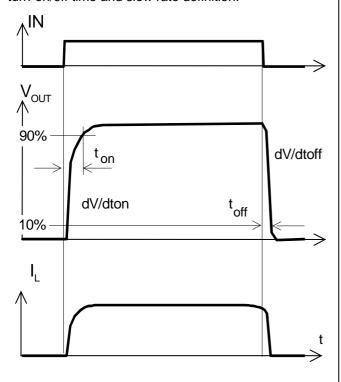
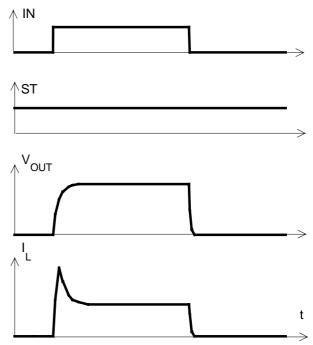
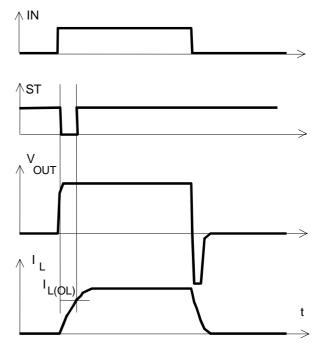


Figure 2b: Switching a lamp:



The initial peak current should be limited by the lamp and not by the current limit of the device.

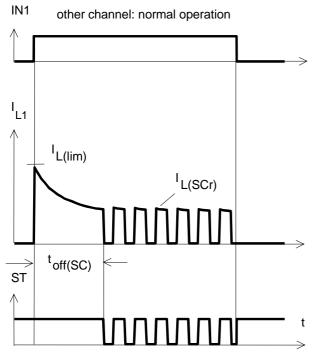
Figure 2c: Switching an inductive load



\*) if the time constant of load is too large, open-load-status may occur

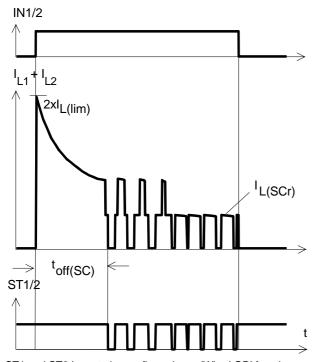
## **SIEMENS**

**Figure 3a:** Turn on into short circuit: shut down by overtemperature, restart by cooling



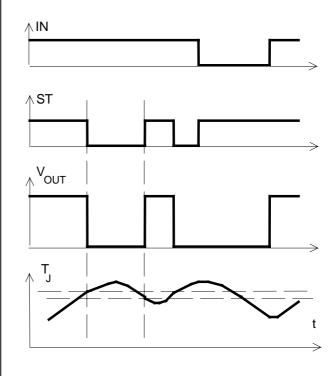
Heating up of the chip may require several milliseconds, depending on external conditions

**Figure 3b:** Turn on into short circuit: shut down by overtemperature, restart by cooling (two parallel switched channels 1 and 2)



ST1 and ST2 have to be configured as a 'Wired OR' function ST1/2 with a single pull-up resistor.

**Figure 4a:** Overtemperature: Reset if  $T_i < T_{it}$ 



**Figure 5a:** Open load: detection in ON-state, open load occurs in on-state

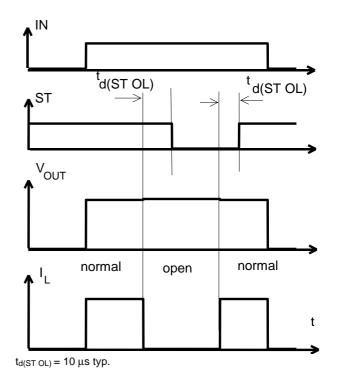
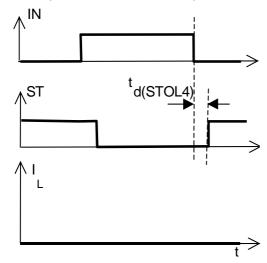




Figure 5b: Open load: turn on/off to open load



## Package and Ordering Code

#### Standard: P-DSO-20-9

Sales Code	BTS 728 L2
Ordering Code	Q67060-S7011-A2

All dimensions in millimetres

0.35x45°
7.8-02

0.35x45°
7.8-02

0.35x45°
7.8-02

10.3±03

10.3±03

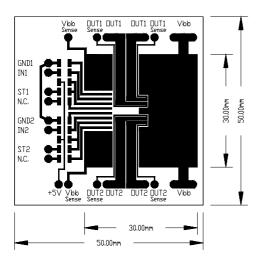
Index Marking

1) Does not include plastic or metal protrusion of 0.15 max. per side
2) Does not include dambar protrusion of 0.05 max. per side

Definition of soldering point with temperature T<sub>s</sub>: upper side of solder edge of device pin 15.



Printed circuit board (FR4, 1.5mm thick, one layer  $70\mu m$ ,  $6cm^2$  active heatsink area) as a reference for max. power dissipation  $P_{tot}$ , nominal load current  $I_{L(NOM)}$  and thermal resistance  $R_{thia}$ 



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